## NSN 5961-01-087-9427

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-087-9427 **Inclosure Material:** Metal **Overall Length:** 0.340 inches **Overall Diameter:** 0.500 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-66 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method:** Unthreaded hole **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon **Power Rating Per Characteristic:** 3.0 watts small-signal input power, common-collector preset **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: pnp **Test Data Document:** 81349-mil-s-19500 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain environmental and performance requirements and test conditions that are shown as "typical", "average", "", etc.). **Terminal Type And Quantity:** 2 uninsulated wire lead and 1 case **Specification Data:** 81349-mil-s-19500/461 government specification Shelf Life: N/a **Unit Of Measure: Demilitarization:** 

No

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